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## TC74VHCT373AF, TC74VHCT373AFW, TC74VHCT373AFT

### Octal D-Type Latch with 3-State Output

The TC74VHCT373A is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and a output enable input ( $\overline{OE}$ ).

When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

The input voltage are compatible with TTL output voltage.

This device may be used as a level converter for interfacing 3.3 V to 5 V system.

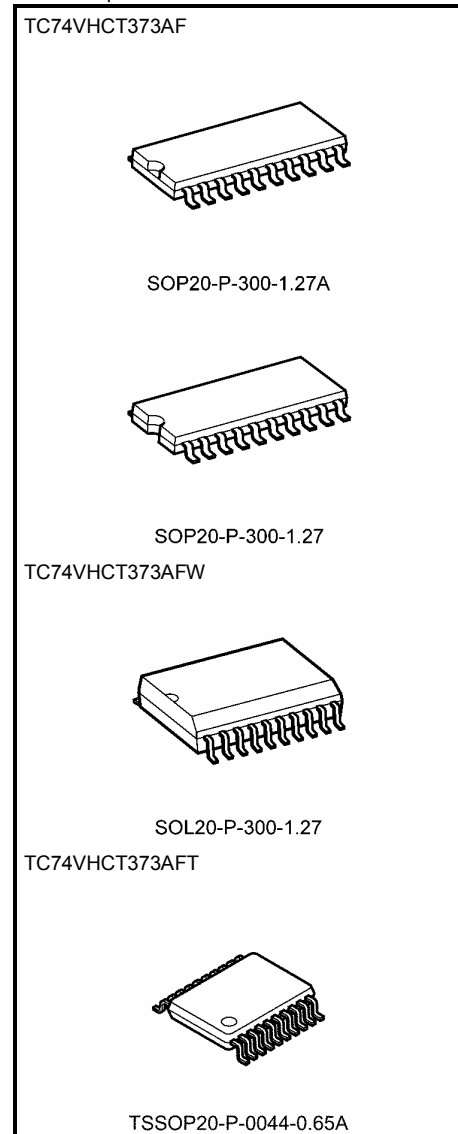
Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, hot board insertion, etc.

Note: Output in off-state

### Features

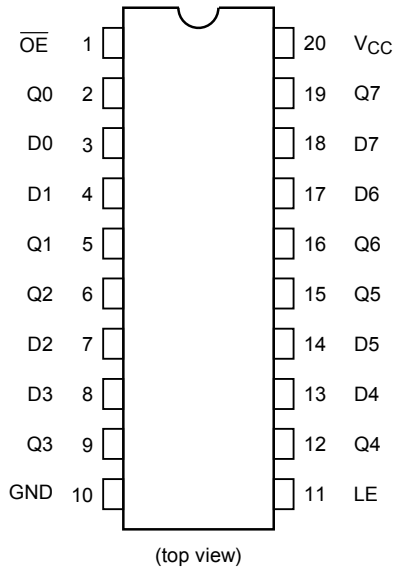
- High speed:  $t_{pd} = 7.7$  ns (typ.) at  $V_{CC} = 5$  V
- Low power dissipation:  $I_{CC} = 4$   $\mu$ A (max) at  $T_a = 25^\circ$ C
- Compatible with TTL outputs:  $V_{IL} = 0.8$  V (max)  
 $V_{IH} = 2.0$  V (min)
- Power down protection is provided on all inputs and outputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Low noise:  $V_{OLP} = 1.6$  V (max)
- Pin and function compatible with the 74 series (74AC/HC/F/ALS/LS etc.) 373 type.

Note: xxxFW (JEDEC SOP) is not available in Japan.

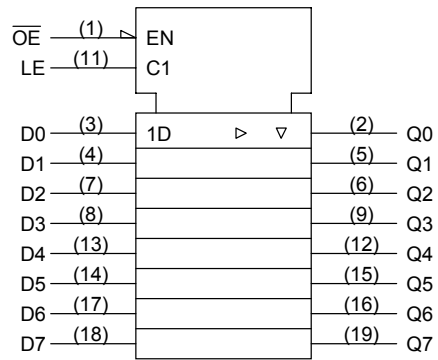


|                      |                 |
|----------------------|-----------------|
| Weight               |                 |
| SOP20-P-300-1.27A    | : 0.22 g (typ.) |
| SOP20-P-300-1.27     | : 0.22 g (typ.) |
| SOL20-P-300-1.27     | : 0.46 g (typ.) |
| TSSOP20-P-0044-0.65A | : 0.08 g (typ.) |

## Pin Assignment



## IEC Logic Symbol



## Truth Table

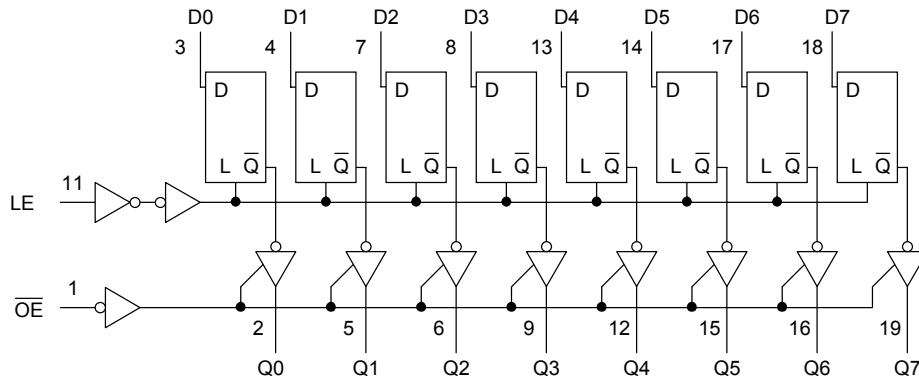
| Inputs          |    |   | Output |
|-----------------|----|---|--------|
| $\overline{OE}$ | LE | D |        |
| H               | X  | X | Z      |
| L               | L  | X | $Q_n$  |
| L               | H  | L | L      |
| L               | H  | H | H      |

X: Don't care

Z: High impedance

$Q_n$ : Q outputs are latched at the time when the LE input is taken to a low logic level.

## System Diagram



## Absolute Maximum Ratings (Note 1)

| Characteristics             | Symbol    | Rating                          | Unit        |
|-----------------------------|-----------|---------------------------------|-------------|
| Supply voltage range        | $V_{CC}$  | -0.5 to 7.0                     | V           |
| DC input voltage            | $V_{IN}$  | -0.5 to 7.0                     | V           |
| DC output voltage           | $V_{OUT}$ | -0.5 to 7.0 (Note 2)            | V           |
|                             |           | -0.5 to $V_{CC} + 0.5$ (Note 3) |             |
| Input diode current         | $I_{IK}$  | -20                             | mA          |
| Output diode current        | $I_{OK}$  | $\pm 20$ (Note 4)               | mA          |
| DC output current           | $I_{OUT}$ | $\pm 25$                        | mA          |
| DC $V_{CC}$ /ground current | $I_{CC}$  | $\pm 75$                        | mA          |
| Power dissipation           | $P_D$     | 180                             | mW          |
| Storage temperature         | $T_{stg}$ | -65 to 150                      | $^{\circ}C$ |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in off-state

Note 3: High or low state.  $I_{OUT}$  absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$

## Recommended Operating Conditions (Note 1)

| Characteristics          | Symbol    | Rating                 | Unit        |
|--------------------------|-----------|------------------------|-------------|
| Supply voltage           | $V_{CC}$  | 4.5 to 5.5             | V           |
| Input voltage            | $V_{IN}$  | 0 to 5.5               | V           |
| Output voltage           | $V_{OUT}$ | 0 to 5.5 (Note 2)      | V           |
|                          |           | 0 to $V_{CC}$ (Note 3) |             |
| Operating temperature    | $T_{opr}$ | -40 to 85              | $^{\circ}C$ |
| Input rise and fall time | dt/dV     | 0 to 20                | ns/V        |

Note 1: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or  $GND$ .

Note 2: Output in off-state

Note 3: High or low state

**Electrical Characteristics**

**DC Characteristics**

| Characteristics                  | Symbol           | Test Condition  |                          | Ta = 25°C           |      |      | Ta = -40 to 85°C |      | Unit  |     |
|----------------------------------|------------------|---|--------------------------|---------------------|------|------|------------------|------|-------|-----|
|                                  |                  |   |                          | V <sub>CC</sub> (V) | Min  | Typ. | Max              | Min  |       | Max |
| High-level input voltage         | V <sub>IH</sub>  | —   |                          | 4.5 to 5.5          | 2.0  | —    | —                | 2.0  | —     | V   |
| Low-level input voltage          | V <sub>IL</sub>  | —   |                          | 4.5 to 5.5          | —    | —    | 0.8              | —    | 0.8   | V   |
| High-level output voltage        | V <sub>OH</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | I <sub>OH</sub> = -50 μA | 4.5                 | 4.40 | 4.50 | —                | 4.40 | —     | V   |
|                                  |                  |   | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.94 | —    | —                | 3.80 | —     |     |
| Low-level output voltage         | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>  | I <sub>OL</sub> = 50 μA  | 4.5                 | —    | 0.0  | 0.1              | —    | 0.1   | V   |
|                                  |                  |   | I <sub>OL</sub> = 8 mA   | 4.5                 | —    | —    | 0.36             | —    | 0.44  |     |
| 3-state output off-state current | I <sub>OZ</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>V <sub>OUT</sub> = V <sub>CC</sub> or GND |                          | 5.5                 | —    | —    | ±0.25            | —    | ±2.50 | μA  |
| Input leakage current            | I <sub>IN</sub>  | V <sub>IN</sub> = 5.5 V or GND  |                          | 0 to 5.5            | —    | —    | ±0.1             | —    | ±1.0  | μA  |
| Quiescent supply current         | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND  |                          | 5.5                 | —    | —    | 4.0              | —    | 40.0  | μA  |
|                                  | I <sub>CCT</sub> | Per input: V <sub>IN</sub> = 3.4 V<br>Other input: V <sub>CC</sub> or GND                         |                          | 5.5                 | —    | —    | 1.35             | —    | 1.50  | mA  |
| Output leakage current           | I <sub>OPD</sub> | V <sub>OUT</sub> = 5.5 V  |                          | 0                   | —    | —    | 0.5              | —    | 5.0   | μA  |

**Timing Requirements (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)**

| Characteristics          | Symbol             | Test Condition |  | Ta = 25°C           |      | Ta = -40 to 85°C | Unit |       |
|--------------------------|--------------------|----------------|--|---------------------|------|------------------|------|-------|
|                          |                    |                |  | V <sub>CC</sub> (V) | Typ. | Limit            |      | Limit |
| Minimum pulse width (LE) | t <sub>w</sub> (H) | —              |  | 5.0 ± 0.5           | —    | 6.5              | 8.5  | ns    |
| Minimum set-up time      | t <sub>s</sub>     | —              |  | 5.0 ± 0.5           | —    | 1.5              | 1.5  | ns    |
| Minimum hold time        | t <sub>h</sub>     | —              |  | 5.0 ± 0.5           | —    | 3.5              | 3.5  | ns    |

## AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics               | Symbol            | Test Condition        | Ta = 25°C           |                     |     | Ta = -40 to 85°C |      | Unit |      |     |
|-------------------------------|-------------------|-----------------------|---------------------|---------------------|-----|------------------|------|------|------|-----|
|                               |                   |                       | V <sub>CC</sub> (V) | C <sub>L</sub> (pF) | Min | Typ.             | Max  |      | Min  | Max |
| Propagation delay time (LE-Q) | t <sub>pLH</sub>  | —                     | 5.0 ± 0.5           | 15                  | —   | 7.7              | 12.3 | 1.0  | 13.5 | ns  |
|                               | t <sub>pHL</sub>  |                       |                     | 50                  | —   | 8.5              | 13.3 | 1.0  | 14.5 |     |
| Propagation delay time (D-Q)  | t <sub>pLH</sub>  | —                     | 5.0 ± 0.5           | 15                  | —   | 5.1              | 8.5  | 1.0  | 9.5  | ns  |
|                               | t <sub>pHL</sub>  |                       |                     | 50                  | —   | 5.9              | 9.5  | 1.0  | 10.5 |     |
| 3-state output enable time    | t <sub>pZL</sub>  | R <sub>L</sub> = 1 kΩ | 5.0 ± 0.5           | 15                  | —   | 6.3              | 10.9 | 1.0  | 12.5 | ns  |
|                               | t <sub>pZH</sub>  |                       |                     | 50                  | —   | 7.1              | 11.9 | 1.0  | 13.5 |     |
| 3-state output disable time   | t <sub>pLZ</sub>  | R <sub>L</sub> = 1 kΩ | 5.0 ± 0.5           | 50                  | —   | 8.8              | 11.2 | 1.0  | 12.0 | ns  |
|                               | t <sub>pHZ</sub>  |                       |                     |                     |     |                  |      |      |      |     |
| Output to output skew         | t <sub>osLH</sub> | (Note 1)              | 5.0 ± 0.5           | 50                  | —   | —                | 1.0  | —    | 1.0  | ns  |
|                               | t <sub>osHL</sub> |                       |                     |                     |     |                  |      |      |      |     |
| Input capacitance             | C <sub>IN</sub>   | —                     | —                   | —                   | 4   | 10               | —    | 10   | pF   |     |
| Output capacitance            | C <sub>OUT</sub>  | —                     | —                   | —                   | 9   | —                | —    | —    | pF   |     |
| Power dissipation capacitance | C <sub>PD</sub>   | (Note 2)              | —                   | —                   | 25  | —                | —    | —    | pF   |     |

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per latch)}$$

And the total C<sub>PD</sub> when n pcs. of latch operate can be gained by the following equation:

$$C_{PD} \text{ (total)} = 14 + 11 \cdot n$$

## Noise Characteristics (input: $t_r = t_f = 3 \text{ ns}$ ) (Note)

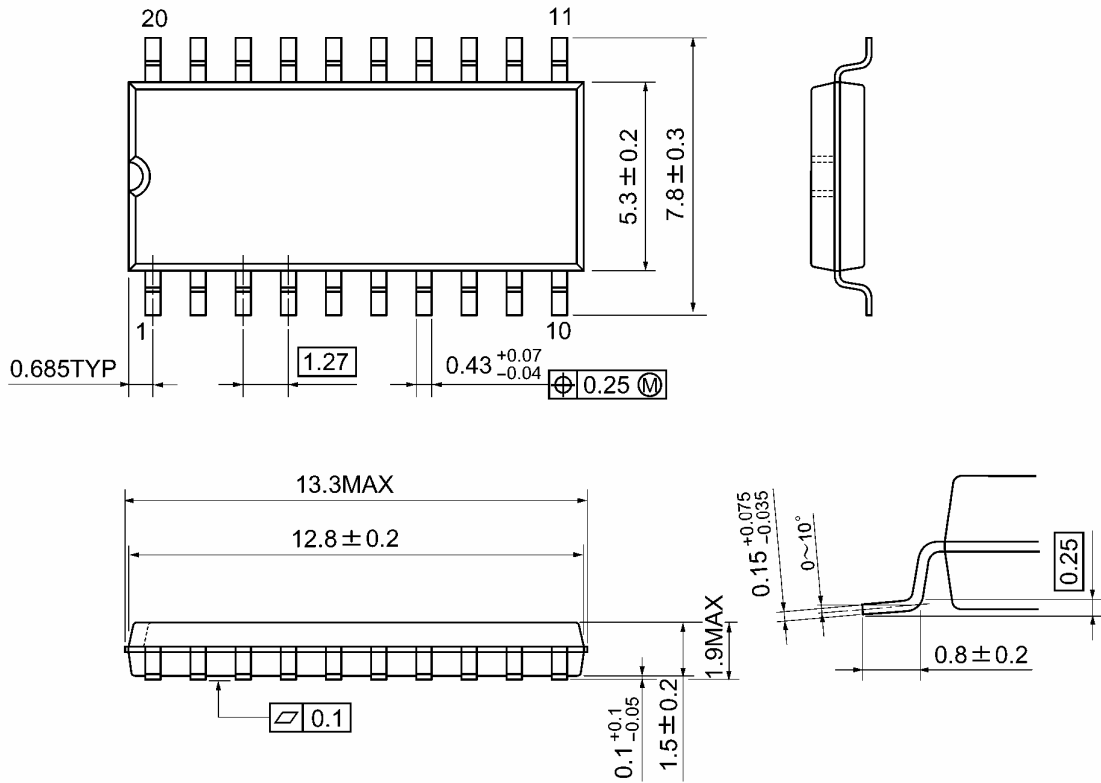
| Characteristics                              | Symbol           | Test Condition         | Ta = 25°C           |                |                | Unit |
|--|------------------|------------------------|---------------------|----------------|----------------|------|
|  |                  |                        | V <sub>CC</sub> (V) | Typ.           | Max            |      |
| Quiet output maximum dynamic V <sub>OL</sub> | V <sub>OLP</sub> | C <sub>L</sub> = 50 pF | 5.0                 | 1.1<br>(1.2)   | 1.5<br>(1.6)   | V    |
| Quiet output minimum dynamic V <sub>OL</sub> | V <sub>OLV</sub> | C <sub>L</sub> = 50 pF | 5.0                 | -1.1<br>(-1.2) | -1.5<br>(-1.6) | V    |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | —              | 2.0            | V    |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | —              | 0.8            | V    |

Note: The value in ( ) only applies to JEDEC SOP (FW) devices.

## Package Dimensions

SOP20-P-300-1.27A

Unit: mm

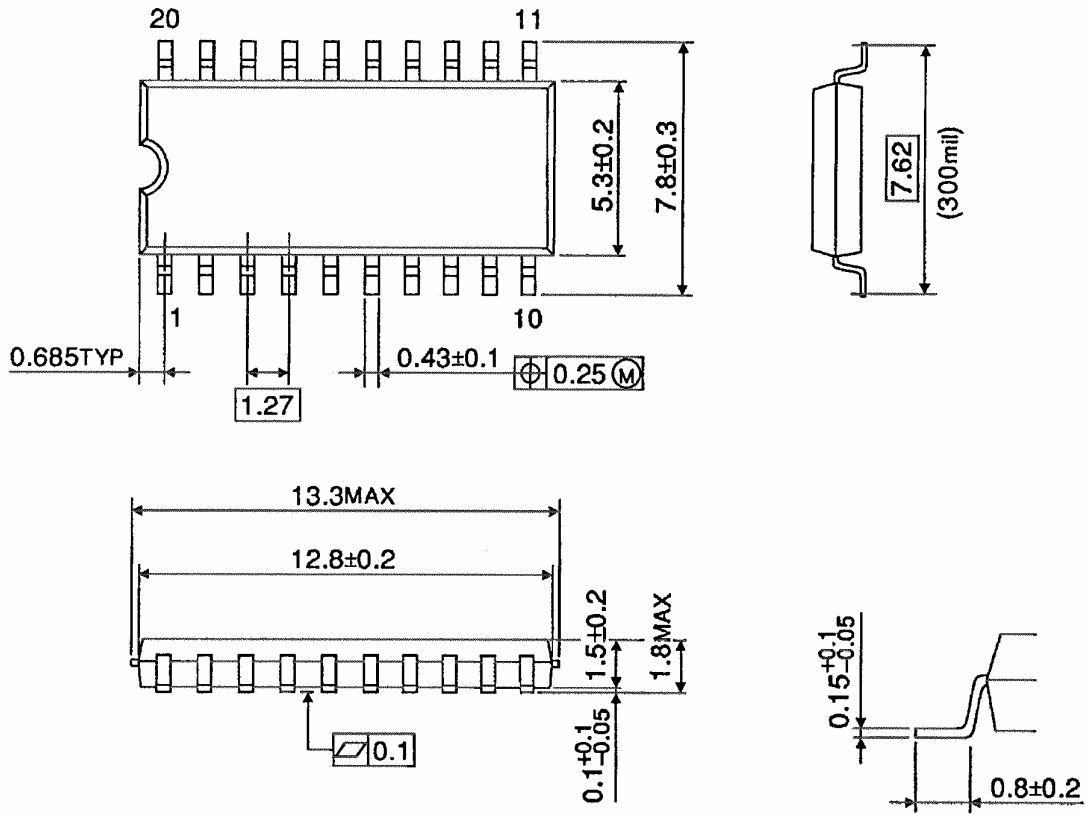


Weight: 0.22 g (typ.)

**Package Dimensions**

SOP20-P-300-1.27

Unit : mm



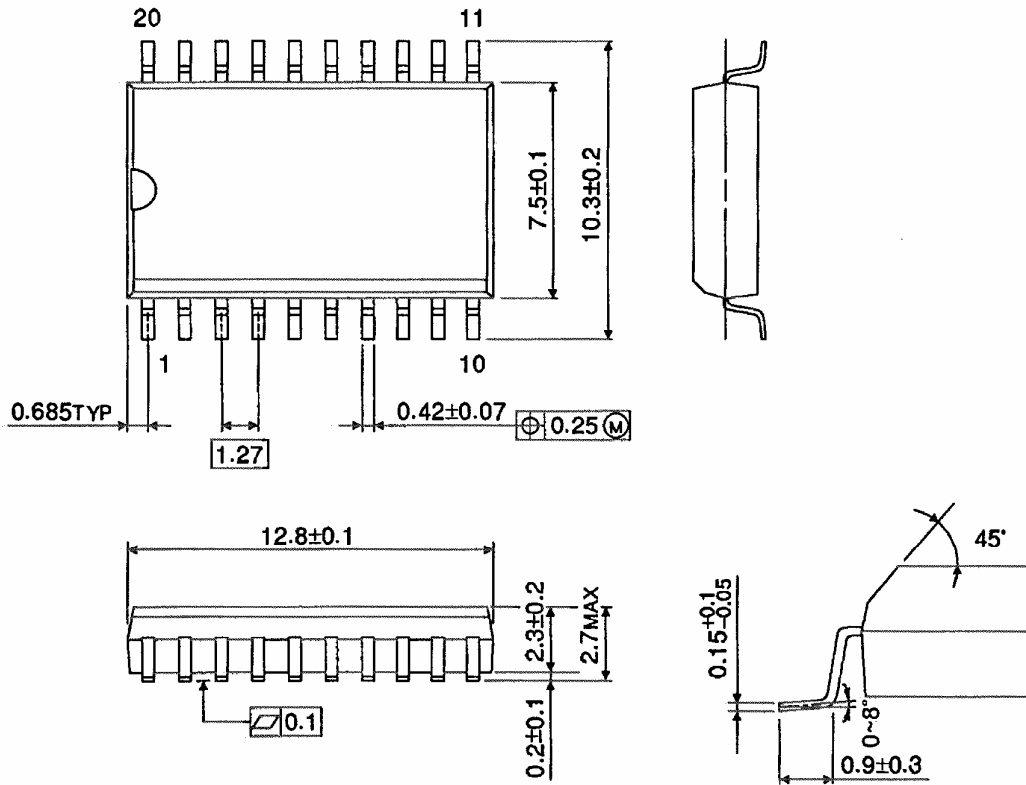
Weight: 0.22 g (typ.)



## Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



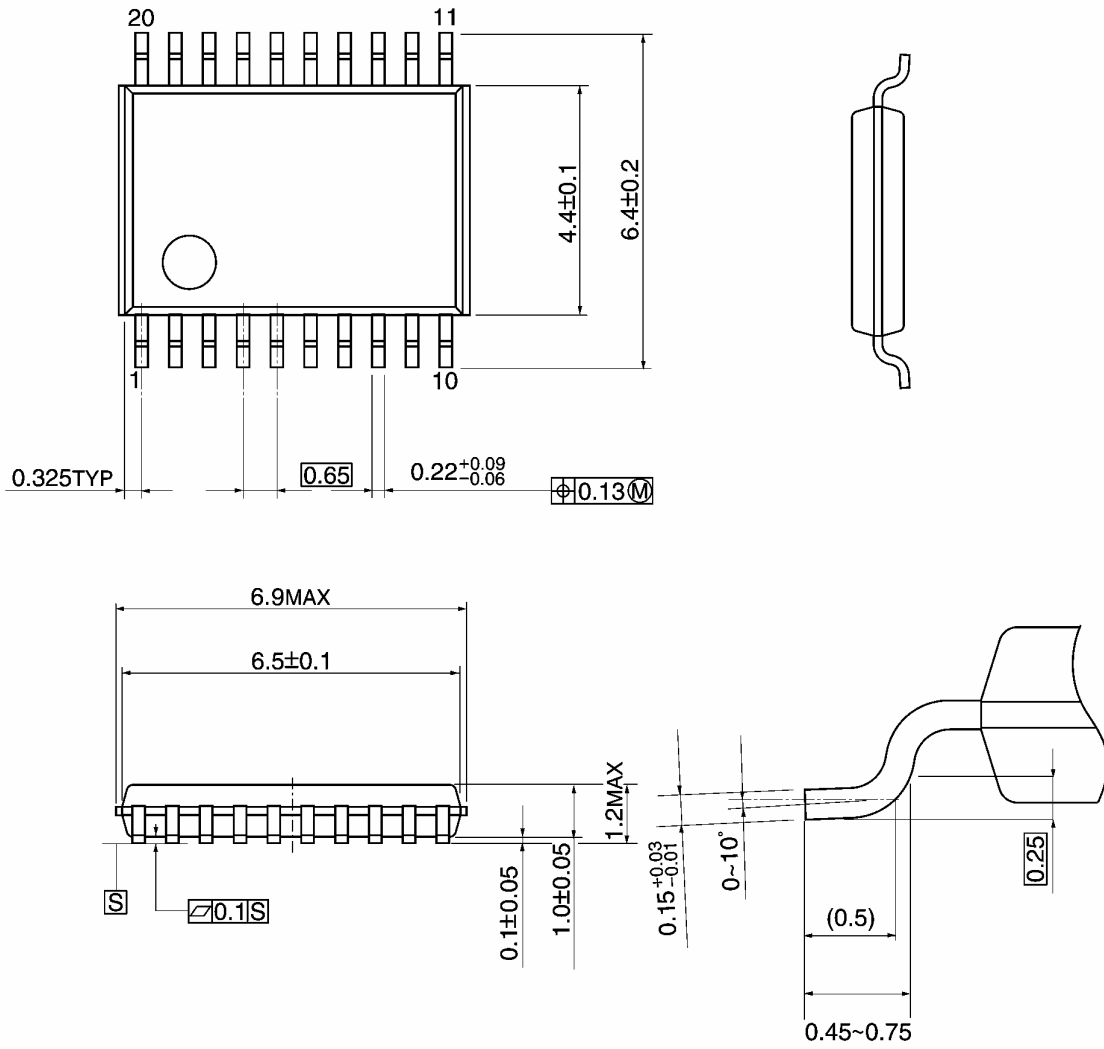
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

**Package Dimensions**

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

**Note: Lead (Pb)-Free Packages****SOP20-P-300-1.27A TSSOP20-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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